NSN 5961-00-416-9684



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-416-9684 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** Airborne radar and miscellaneous electronic equipment **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and burn in and gold plated leads **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage all transistor and 50.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 30.00 milliamperes gate current all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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